



Optoelectronic Devices Based On Thin Single-Crystalline Semiconductor Films And Non-Epitaxial Optical Cavities

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The Invention

Optoelectronic devices that use very thin single-crystalline inorganic semiconductor films as phonon-absorbing layers in combination with non-lattice optical cavities are provided.

Additional Information

For More Information About the Inventors

- [Zhenqiang Ma](#)
- [Zongfu Yu](#)

Publications

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Tech Fields

- [Analytical Instrumentation, Methods & Materials : Optics](#)
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